

Po-Wen Chiu

List of Publications by Year in descending order

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105
papers

6,858
citations

66234

42
h-index

58464

82
g-index

105
all docs

105
docs citations

105
times ranked

11155
citing authors

#	ARTICLE	IF	CITATIONS
1	Graphene Annealing: How Clean Can It Be?. Nano Letters, 2012, 12, 414-419.	4.5	801
2	Controllable graphene N-doping with ammonia plasma. Applied Physics Letters, 2010, 96, .	1.5	446
3	Single-Layer ReS ₂ : Two-Dimensional Semiconductor with Tunable In-Plane Anisotropy. ACS Nano, 2015, 9, 11249-11257.	7.3	353
4	Clean Transfer of Graphene for Isolation and Suspension. ACS Nano, 2011, 5, 2362-2368.	7.3	285
5	V2O5 nanofibre sheet actuators. Nature Materials, 2003, 2, 316-319.	13.3	248
6	Structural and Chemical Dynamics of Pyridinic-Nitrogen Defects in Graphene. Nano Letters, 2015, 15, 7408-7413.	4.5	204
7	Interconnection of carbon nanotubes by chemical functionalization. Applied Physics Letters, 2002, 80, 3811-3813.	1.5	188
8	Three-fold rotational defects in two-dimensional transition metal dichalcogenides. Nature Communications, 2015, 6, 6736.	5.8	179
9	High-Mobility InSe Transistors: The Role of Surface Oxides. ACS Nano, 2017, 11, 7362-7370.	7.3	177
10	Flexible ferroelectric element based on van der Waals heteroepitaxy. Science Advances, 2017, 3, e1700121.	4.7	174
11	Twisting Bilayer Graphene Superlattices. ACS Nano, 2013, 7, 2587-2594.	7.3	173
12	High Mobility Flexible Graphene Field-Effect Transistors with Self-Healing Gate Dielectrics. ACS Nano, 2012, 6, 4469-4474.	7.3	169
13	Growth and electrical transport of germanium nanowires. Journal of Applied Physics, 2001, 90, 5747-5751.	1.1	152
14	Metal-Free Growth of Nanographene on Silicon Oxides for Transparent Conducting Applications. Advanced Functional Materials, 2012, 22, 2123-2128.	7.8	150
15	Remote Catalyzation for Direct Formation of Graphene Layers on Oxides. Nano Letters, 2012, 12, 1379-1384.	4.5	146
16	Magnetotransport at Domain Walls in BiFeO_3 . Physical Review Letters, 2012, 108, 067203.	2.9	131
17	Chemical functionalization of single walled carbon nanotubes. Current Applied Physics, 2002, 2, 497-501.	1.1	110
18	van der Waal Epitaxy of Flexible and Transparent VO ₂ Film on Muscovite. Chemistry of Materials, 2016, 28, 3914-3919.	3.2	105

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19	Tuning of Charge Densities in Graphene by Molecule Doping. <i>Advanced Functional Materials</i> , 2011, 21, 2687-2692.	7.8	99
20	Heteroepitaxy of Fe ₃ O ₄ /Muscovite: A New Perspective for Flexible Spintronics. <i>ACS Applied Materials & Interfaces</i> , 2016, 8, 33794-33801.	4.0	99
21	Intralayer and interlayer electron-phonon interactions in twisted graphene heterostructures. <i>Nature Communications</i> , 2018, 9, 1221.	5.8	93
22	Gigahertz Flexible Graphene Transistors for Microwave Integrated Circuits. <i>ACS Nano</i> , 2014, 8, 7663-7670.	7.3	92
23	Ferroelectric Control of the Conduction at the LaAlO ₃ /SrTiO ₃ Heterointerface. <i>Advanced Materials</i> , 2013, 25, 3357-3364.	11.1	90
24	Photogating WS ₂ Photodetectors Using Embedded WSe ₂ Charge Puddles. <i>ACS Nano</i> , 2020, 14, 4559-4566.	7.3	87
25	Van der Waals epitaxy of functional MoO ₂ film on mica for flexible electronics. <i>Applied Physics Letters</i> , 2016, 108, .	1.5	81
26	Oxide Heteroepitaxy for Flexible Optoelectronics. <i>ACS Applied Materials & Interfaces</i> , 2016, 8, 32401-32407.	4.0	81
27	Exploring the Single Atom Spin State by Electron Spectroscopy. <i>Physical Review Letters</i> , 2015, 115, 206803.	2.9	80
28	Nonlinear Behavior in the Thermopower of Doped Carbon Nanotubes Due to Strong, Localized States. <i>Nano Letters</i> , 2003, 3, 839-842.	4.5	77
29	Fast growth of large-grain and continuous MoS ₂ films through a self-capping vapor-liquid-solid method. <i>Nature Communications</i> , 2020, 11, 3682.	5.8	76
30	Temperature-induced change from p to n conduction in metallofullerene nanotube peapods. <i>Applied Physics Letters</i> , 2001, 79, 3845-3847.	1.5	75
31	Stable 1T Tungsten Disulfide Monolayer and Its Junctions: Growth and Atomic Structures. <i>ACS Nano</i> , 2018, 12, 12080-12088.	7.3	74
32	A novel artificial synapse with dual modes using bilayer graphene as the bottom electrode. <i>Nanoscale</i> , 2017, 9, 9275-9283.	2.8	70
33	Robust room temperature valley polarization in monolayer and bilayer WS ₂ . <i>Nanoscale</i> , 2016, 8, 6035-6042.	2.8	68
34	Fully Transparent Resistive Memory Employing Graphene Electrodes for Eliminating Undesired Surface Effects. <i>Proceedings of the IEEE</i> , 2013, 101, 1732-1739.	16.4	63
35	Growth and Raman Spectra of Single-Crystal Trilayer Graphene with Different Stacking Orientations. <i>ACS Nano</i> , 2014, 8, 10766-10773.	7.3	56
36	In situ observation of step-edge in-plane growth of graphene in a STEM. <i>Nature Communications</i> , 2014, 5, 4055.	5.8	55

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37	In Situ Tuning of Switching Window in a Gate-Controlled Bilayer Graphene Electrode Resistive Memory Device. <i>Advanced Materials</i> , 2015, 27, 7767-7774.	11.1	54
38	Design of Core-Shell Quantum Dots 3D WS ₂ Nanowall Hybrid Nanostructures with High-Performance Bifunctional Sensing Applications. <i>ACS Nano</i> , 2020, 14, 12668-12678.	7.3	49
39	Graphene-Transition Metal Dichalcogenide Heterojunctions for Scalable and Low-Power Complementary Integrated Circuits. <i>ACS Nano</i> , 2020, 14, 985-992.	7.3	46
40	Surface Oxidation Doping to Enhance Photogenerated Carrier Separation Efficiency for Ultrahigh Gain Indium Selenide Photodetector. <i>ACS Photonics</i> , 2017, 4, 2930-2936.	3.2	44
41	End-Bonded Metal Contacts on WSe ₂ Field-Effect Transistors. <i>ACS Nano</i> , 2019, 13, 8146-8154.	7.3	44
42	Ultrafast Monolayer In/Gr-WS ₂ -Gr Hybrid Photodetectors with High Gain. <i>ACS Nano</i> , 2019, 13, 3269-3279.	7.3	44
43	High-Performance Organic Light-Emitting Diode with Substitutionally Boron-Doped Graphene Anode. <i>ACS Applied Materials & Interfaces</i> , 2017, 9, 14998-15004.	4.0	43
44	Direct growth of self-crystallized graphene and graphite nanoballs with Ni vapor-assisted growth: From controllable growth to material characterization. <i>Scientific Reports</i> , 2014, 4, 4739.	1.6	42
45	Scalable Graphite/Copper Bishell Composite for High-Performance Interconnects. <i>ACS Nano</i> , 2014, 8, 275-282.	7.3	41
46	Ultrafast and Low Temperature Synthesis of Highly Crystalline and Patternable Few-Layers Tungsten Diselenide by Laser Irradiation Assisted Selenization Process. <i>ACS Nano</i> , 2015, 9, 4346-4353.	7.3	39
47	Unexpected Huge Dimerization Ratio in One-Dimensional Carbon Atomic Chains. <i>Nano Letters</i> , 2017, 17, 494-500.	4.5	35
48	Layer-Dependent Optical Conductivity in Atomic Thin WS ₂ by Reflection Contrast Spectroscopy. <i>ACS Applied Materials & Interfaces</i> , 2014, 6, 16020-16026.	4.0	34
49	Origin of van Hove singularities in twisted bilayer graphene. <i>Carbon</i> , 2015, 90, 138-145.	5.4	33
50	Band-Structure Modulation in Carbon Nanotube T Junctions. <i>Physical Review Letters</i> , 2004, 92, 246802.	2.9	32
51	Transition from direct tunneling to field emission in carbon nanotube intramolecular junctions. <i>Applied Physics Letters</i> , 2008, 92, 042107.	1.5	30
52	Scalable van der Waals Heterojunctions for High-Performance Photodetectors. <i>ACS Applied Materials & Interfaces</i> , 2017, 9, 36181-36188.	4.0	29
53	Electric control of valley polarization in monolayer WSe ₂ using a van der Waals magnet. <i>Nature Nanotechnology</i> , 2022, 17, 721-728.	15.6	28
54	Temperature dependence of conductance character in nanotube peapods. <i>Applied Physics A: Materials Science and Processing</i> , 2003, 76, 463-467.	1.1	27

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55	All-carbon field emission device by direct synthesis of graphene and carbon nanotube. <i>Diamond and Related Materials</i> , 2013, 31, 42-46.	1.8	27
56	Attenuation of electromagnetic waves by carbon nanotube composites. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2008, 40, 2425-2429.	1.3	26
57	Cathodic plasma-induced syntheses of graphene nanosheet/MnO ₂ /WO ₃ architectures and their use in supercapacitors. <i>Electrochimica Acta</i> , 2020, 342, 136043.	2.6	25
58	Transparent Antiradiative Ferroelectric Heterostructure Based on Flexible Oxide Heteroepitaxy. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 30574-30580.	4.0	24
59	Surface plasma-induced tunable nitrogen doping through precursors provides 1T-2H MoSe ₂ /graphene sheet composites as electrocatalysts for the hydrogen evolution reaction. <i>Electrochimica Acta</i> , 2022, 426, 140767.	2.6	24
60	Postsynthesis of h-BN/Graphene Heterostructures Inside a STEM. <i>Small</i> , 2016, 12, 252-259.	5.2	23
61	High-Mobility InSe Transistors: The Nature of Charge Transport. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 35969-35976.	4.0	23
62	Gating Electron-Hole Asymmetry in Twisted Bilayer Graphene. <i>ACS Nano</i> , 2014, 8, 6962-6969.	7.3	22
63	Inverse paired-pulse facilitation in neuroplasticity based on interface-boosted charge trapping layered electronics. <i>Nano Energy</i> , 2020, 77, 105258.	8.2	22
64	High-performance and high-sensitivity applications of graphene transistors with self-assembled monolayers. <i>Biosensors and Bioelectronics</i> , 2016, 77, 1008-1015.	5.3	21
65	A Graphene-Based Filament Transistor with Sub-10 mVdec ⁻¹ Subthreshold Swing. <i>Advanced Electronic Materials</i> , 2018, 4, 1700608.	2.6	21
66	Twisted bilayer graphene photoluminescence emission peaks at van Hove singularities. <i>Journal of Physics Condensed Matter</i> , 2018, 30, 175302.	0.7	21
67	Gigahertz Field-Effect Transistors with CMOS-Compatible Transfer-Free Graphene. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 6336-6343.	4.0	20
68	Photoactive Electro-Controlled Visual Perception Memory for Emulating Synaptic Metaplasticity and Hebbian Learning. <i>Advanced Functional Materials</i> , 2021, 31, 2105345.	7.8	18
69	Characterization of Graphene Grown on Bulk and Thin Film Nickel. <i>Langmuir</i> , 2011, 27, 13748-13753.	1.6	17
70	Conduction control at ferroic domain walls via external stimuli. <i>Nanoscale</i> , 2014, 6, 10524-10529.	2.8	17
71	Rational Design on Wrinkle-Less Transfer of Transition Metal Dichalcogenide Monolayer by Adjustable Wettability-Assisted Transfer Method. <i>Advanced Functional Materials</i> , 2021, 31, 2104978.	7.8	17
72	Substitutional boron-doping of carbon nanotubes. <i>Current Applied Physics</i> , 2002, 2, 473-477.	1.1	13

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73	Scanning Moiré Fringe Method: A Superior Approach to Perceive Defects, Interfaces, and Distortion in 2D Materials. ACS Nano, 2020, 14, 6034-6042.	7.3	13
74	Formation of Highly Doped Nanostripes in 2D Transition Metal Dichalcogenides via a Dislocation Climb Mechanism. Advanced Materials, 2021, 33, e2007819.	11.1	13
75	Probing interlayer coupling in twisted single-crystal bilayer graphene by Raman spectroscopy. Journal of Raman Spectroscopy, 2014, 45, 912-917.	1.2	12
76	Carbon nanotube nanocontact in T-junction structures. Applied Physics Letters, 2007, 91, 102109.	1.5	11
77	Scalable T-Gate Aligned WS ₂ /Gr Radio-Frequency Field-Effect Transistors. ACS Applied Electronic Materials, 2020, 2, 3898-3905.	2.0	11
78	WS ₂ /WSe ₂ Nanodot Composite Photodetectors for Fast and Sensitive Light Detection. ACS Applied Electronic Materials, 2021, 3, 4291-4299.	2.0	11
79	High-performance carbon nanotube network transistors for logic applications. Applied Physics Letters, 2008, 92, 063511.	1.5	10
80	Mimic Drug Dosage Modulation for Neuroplasticity Based on Charge-Trap Layered Electronics. Advanced Functional Materials, 2021, 31, 2005182.	7.8	10
81	Hybrid ZnO NR/graphene structures as advanced optoelectronic devices with high transmittance. Nanoscale Research Letters, 2013, 8, 350.	3.1	9
82	Raman Excitation Profile of the G-band Enhancement in Twisted Bilayer Graphene. Brazilian Journal of Physics, 2017, 47, 589-593.	0.7	9
83	Oxidation and Degradation of WS ₂ Monolayers Grown by NaCl-Assisted Chemical Vapor Deposition: Mechanism and Prevention. Nanoscale, 2021, 13, 16629-16640.	2.8	7
84	Resonance Raman enhancement by the intralayer and interlayer electron-phonon processes in twisted bilayer graphene. Scientific Reports, 2021, 11, 17206.	1.6	7
85	Modifying optical properties of GaN nanowires by Ga ₂ O ₃ overgrowth. Journal of Vacuum Science and Technology B: Nanotechnology and Microelectronics, 2012, 30, .	0.6	6
86	Characterization of Graphene and Transition Metal Dichalcogenide at the Atomic Scale. Journal of the Physical Society of Japan, 2015, 84, 121005.	0.7	6
87	Embedment of Multiple Transition Metal Impurities into WS ₂ Monolayer for Bandstructure Modulation. Small, 2021, 17, e2007171.	5.2	6
88	Fabrication and characteristics of ultrashort-channel carbon nanotube field-effect transistors. Applied Physics Letters, 2008, 92, 152111.	1.5	5
89	Two-dimensional iodine-monofluoride epitaxy on WSe ₂ . Npj 2D Materials and Applications, 2021, 5, .	3.9	5
90	On-Wafer FinFET-Based EUV/eBeam Detector Arrays for Advanced Lithography Processes. IEEE Transactions on Electron Devices, 2020, 67, 2406-2413.	1.6	4

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91	WSe ₂ /WS ₂ Heterobilayer Nonvolatile Memory Device with Boosted Charge Retention. ACS Applied Materials & Interfaces, 2022, 14, 3467-3475.	4.0	4
92	Tailoring point electron sources of individual carbon nanotubes. Applied Physics Letters, 2010, 97, 073119.	1.5	3
93	Effect of adsorbents on electronic transport in graphene. , 2014, , 265-291.		3
94	A Graphene/Polycrystalline Silicon Photodiode and Its Integration in a Photodiodeâ€“Oxideâ€“Semiconductor Field Effect Transistor. Micromachines, 2020, 11, 596.	1.4	3
95	Carbon Nanotube T Junctions: Formation and Properties. Journal of Nanoscience and Nanotechnology, 2008, 8, 88-98.	0.9	2
96	Artificial mechanoreceptor based on van der Waals stacking structure. Matter, 2021, 4, 1598-1610.	5.0	2
97	Memory Devices: In Situ Tuning of Switching Window in a Gate-Controlled Bilayer Graphene-Electrode Resistive Memory Device (Adv. Mater. 47/2015). Advanced Materials, 2015, 27, 7766-7766.	11.1	1
98	Enhanced hot luminescence at van Hove singularities in twisted bilayer graphene. , 2017, , .		1
99	Co Silicide With Low Contact Resistivity Formed by Atomic Layer Deposited Cobalt and Subsequent Annealing. IEEE Electron Device Letters, 2020, 41, 139-142.	2.2	1
100	Nearly Epitaxial Low-Resistive Co Germanide Formed by Atomic Layer Deposited Cobalt and Laser Thermal Annealing. IEEE Electron Device Letters, 2020, 41, 272-275.	2.2	1
101	Defect Engineering for Graphene Tunable Doping. Materials Research Society Symposia Proceedings, 2011, 1283, 1.	0.1	0
102	RESONANCE RAMAN SPECTROSCOPY IN TWISTED BILAYER GRAPHENE. , 2013, , .		0
103	Integrated silicon optical modulators. , 2016, , .		0
104	Photoinduced Intersubband Absorption and Enhanced Photobleaching in Twisted Bilayer Graphene. , 2021, , .		0
105	Photoinduced Intersubband Absorption and Enhanced Photobleaching in Twisted Bilayer Graphene. , 2020, , .		0